SQJ164ELP

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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET



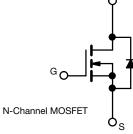
PRODUCT SUMMARY	
V _{DS} (V)	60
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.013
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.012
I _D (A)	75
Configuration	Single
Package	PowerPAK SO-8L

FEATURES

- TrenchFET[®] Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
 Material categorization:



for definitions of compliance please see www.vishay.com/doc?99912



ABSOLUTE MAXIMUM RATINGS	S (T _C = 25 °C, unless	otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	V	
Gate-source voltage		V _{GS}	V _{GS} ± 20		
Continuous drain current	T _C = 25 °C	T _C = 25 °C			
	T _C = 125 °C	I _D	43		
Continuous source current (diode conduction)		I _S	75	А	
Pulsed drain current ^a		I _{DM}	130		
Single pulse avalanche current		I _{AS}	31		
Single pulse avalanche energy		E _{AS}	48	mJ	
Maximum power dissipation	T _C = 25 °C	P	187	W	
	T _C = 125 °C	P _D	62	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) c			260	C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^b	R _{thJA}	42	°C/W	
Junction-to-case (drain)		R _{thJC}	0.8	0/10	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. When mounted on 1" square PCB (FR4 material)

c. See solder profile (<u>www.vishay.com/doc?73257</u>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		60	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA		1.5	2.0	2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	μA
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	30	-	-	Α
Duria a suma an atata mariatana a		V _{GS} = 10 V	I _D = 15 A	-	0.009	0.012	
	P	$V_{GS} = 10 V$	I _D = 15 A, T _J = 125 °C	-	-	0.025	Ω
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 15 A, T _J = 175 °C	-	-	0.033	
		V _{GS} = 4.5 V		-	0.010	0.013	
Forward transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 10 A		-	79	-	S
Dynamic ^b		•		•	•	•	
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	2215	3100	pF
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	202	283	
Reverse transfer capacitance	C _{rss}			-	69	97	
Total gate charge ^c	Qg			-	38	57	
Gate-source charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, I_{D} = 15 \text{ A}$	-	8	-	nC
Gate-drain charge ^c	Q _{gd}			-	6	-	
Gate resistance	R _g	f = 1 MHz		0.9	1.8	2.7	Ω
Turn-on delay time ^c	t _{d(on)}			-	11	17	<u> </u>
Rise time ^c	t _r	- V _{DD} =	$V_{DD} = 30 \text{ V}, \text{ R}_{L} = 2.0 \Omega$		4	6	- ns
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 15 \text{ A}, V_{\text{GEN}} = 10 \text{ V}, \text{R}_g = 1 \Omega$		-	29	44	
Fall time ^c	t _f			-	3	5	
Source-Drain Diode Ratings and Chara	acteristics ^b				•		
Pulsed current ^a	I _{SM}				-	130	A
Forward voltage	V _{SD}	I _F = 10 A, V _{GS} = 0 V		-	-	1.1	V
Body diode reverse recovery time	t _{rr}	I _F = 10 A, dl/dt = 100 A/μs		-	21	42	ns
Body diode reverse recovery charge	Q _{rr}			-	18	36	nC
Reverse recovery fall time	ta			-	14	-	l
Reverse recovery rise time	t _b			-	7	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	1.8	-	А

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

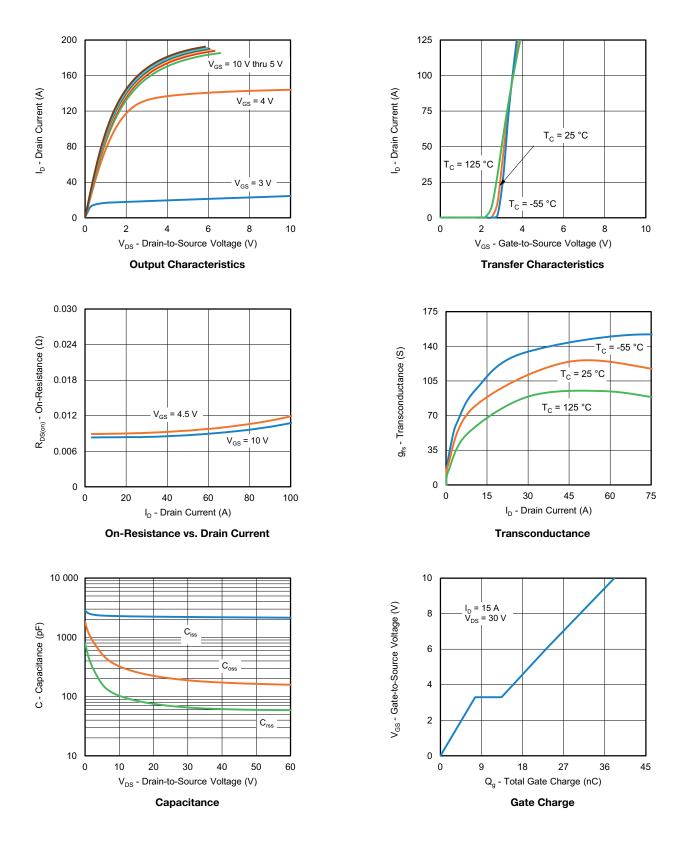
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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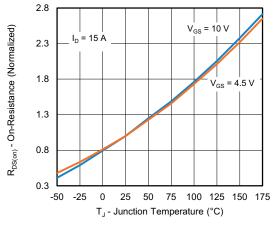
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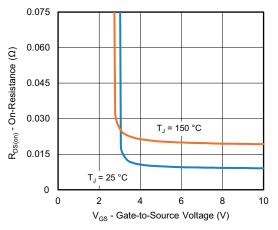
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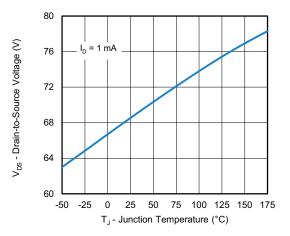
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



On-Resistance vs. Junction Temperature

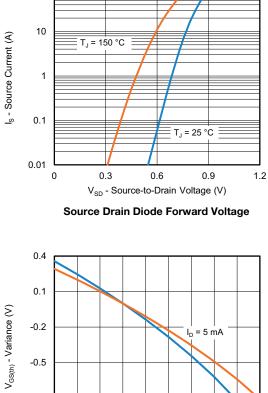


On-Resistance vs. Gate-to Source Voltage

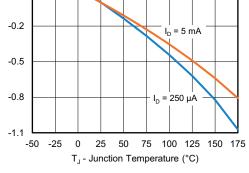


Drain Source Breakdown vs. Junction Temperature Note

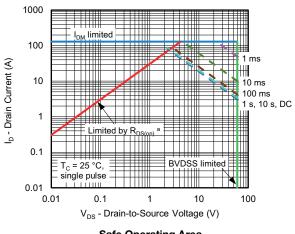
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



100



Threshold Voltage



Safe Operating Area

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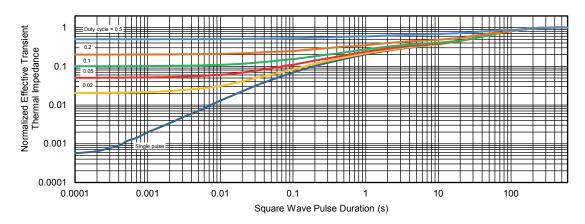
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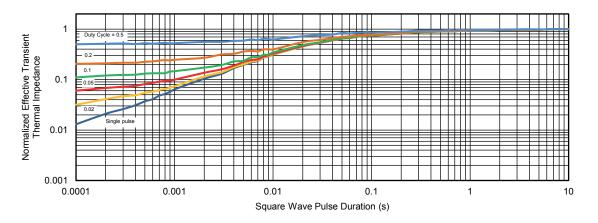
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

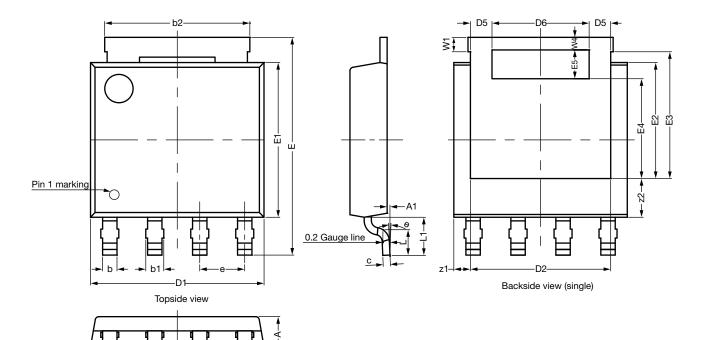
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77465.

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PowerPAK[®] SO-8L (PPKSO8LWLA) Case Outline 3



DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
А	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

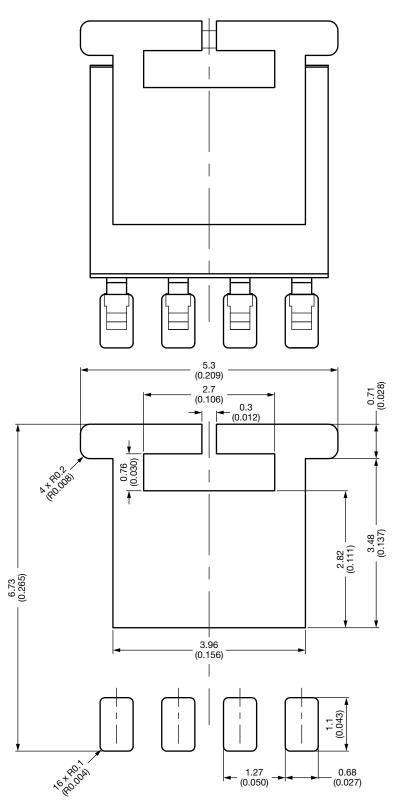
Note

• Millimeter will govern

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Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)

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